PCN	Num	ber:	20240430000.1				PCN Date:			April 30, 2024	
Title	o:	Qualification	nalification of RFAB using qualified Process Technology, Die Revision,							e Revision,	
1161	C.	Datasheet,	and additi	onal	Assembly site	e op	tions for	sele	ct d	evices	
Cus	tomer	Contact:	Change M	anag	gement Team		Dept:			Quality Services	
Pro	posed	1 st Ship	July 20 2	N24			mple red			May 30, 2024*	
Dat	e:		July 29, 2024 acce			accepted until:		til:	14ay 50, 2024		
*Sample requests received after May 30, 2024 will not be supported.											
Cha	nge T	ype:									
\boxtimes	Asser	nbly Site		\boxtimes	Design				Wafer Bump Material		
	Assembly Process			\boxtimes	Data Sheet				Wafer Bump Process		
	Assembly Materials				Part number change			Wa	Wafer Fab Site		
	Mechanical Specification				Test Site			Wa	/afer Fab Material		
	Packi	ng/Shipping	/Labeling		Test Process	3		\boxtimes	Wa	afer Fab Process	
					DON D						

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of its RFAB fabrication facility as an additional Wafer Fab option in addition to a new Assembly site (CDAT) for the devices listed in the "Product Affected" section.

	Current Fab	Site	Additional Fab Site			
Fab Site	Process	Wafer Diameter	Fab Site	Process	Wafer Diameter	
MIHO8	LBC7	200 mm	RFAB	LBC9	200 mm	
RFAB	LBC7	300 mm	KFAD	LBC9	300 mm	

The die was also changed as a result of the process change.

With CDAT being added as a new Assembly site in addition to JCETCZ and TIPI, there are no new BOM materials being introduced.

The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The links to the revised datasheets are available in the table below.



TPS562201, TPS562208 SLVSD91C - DECEMBER 2015 - REVISED APRIL 2024

С	hanges from Revision B (September 2020) to Revision C (April 2024)	Page
•	Updated trademark information	1
•	Added WEBENCH information throughout the document	
•	Changed low shutdown current from less than 10µA to less than 20µA	1
•	Updated the document title	1
•	Updated Device Information table format	1
•	Changed VBST (vs SW) and VFB MAX from 6.5 to 6	4
•	Changed Human-body model (HBM) value from 3000 to 2000	4
•	Changed VBST (vs SW) MAX from 6.0 to 5.5	4
•	Updated specifications in the Electrical Characteristics table	5
•	Updated Figure 5-1 and Figure 5-2	6
•	Updated the Current Protection section	10

С	hanges from Revision * (December 2015) to Revision A (April 2024)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Changed low shutdown current from less than 10µA to 20µA	1
•	Added WEBENCH information throughout the document	1
•	Updated trademark information	1
	Updated Device Information table format	
	Changed VBST (vs SW) and VFB MAX from 6.5 to 6	
	Changed Human-body model (HBM) value from 3000 to 2000	
	Changed VBST (vs SW) MAX from 6.0 to 5.5	
	Updated Specifications in the Electrical Characteristics table	
	Updated Figure 5-1 and Figure 5-2	
	Updated the Current Protection section	

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet
TPS56220x	SLVSD91B	SLVSD91C	http://www.ti.com/product/TPS562201
TPS56320x	SLVSD90	SLVSD90A	http://www.ti.com/product/TPS563201

Qual details are provided in the Qual Data Section.

Reason for Change:

Continuity of Supply

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
No Change	No Change		igert No Change

Changes to product identification resulting from this PCN:

Fab Site

Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City	
MIHO8	MH8	JPN	Ibaraki	
RFAB	RFB	USA	Richardson	

Die Rev:

Current	New		
Die Rev [2P]	Die Rev [2P]		
Δ	^		

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City	
JCETCZ	JCC	CHN	Chuzhou	
TIPI	PHI	PHL	Baguio City	
CDAT	CDA	CHN	Chengdu	

Sample product shipping label (not actual product label):

TEXAS INSTRUMENTS

MADE IN: Malaysia 2DC: 2Q;

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

5A (L)T0:39750 LBL:



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812

(2P) REV: (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

TPS562201DDCR	TPS562208DDCR	TPS563201DDCR	TPS563208DDCR	
TPS562201DDCT	TPS562208DDCT	TPS563201DDCT	TPS563208DDCT	

Qualification Results

Туре	#	Test Name	Condition	Duration	Qual Device: TPS563201DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: <u>TPS51393RJER</u>	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	1/77/0	-
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	-	-	-	3/231/0
UHAST	A3	Unbiased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	3/231/0	3/231/0	-	1/77/0	-
TC	A4	Temperature Cycle	-55C/125C	700 Cycles	1/77/0	-	-	3/231/0	3/231/0	-
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	-	-	3/231/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	1/77/0	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	3/231/0	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: TPS563201DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: TPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	-	3/231/0	1/77/0	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	-	3/2400/0	-	-
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB- Free Solder;	-	-	3/66/0	3/66/0	-	-	1/22/0
PD	C4	Physical Dimensions	(per mechanical drawing)	-	-	-	-	1/5/0	-	-
ESD	E2	ESD CDM	-	1500 Volts	1/3/0	-	-	-	1/3/0	-
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-	-	1/3/0	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-	1/3/0	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	3/90/0	1/30/0	-
FTY	E6	Final Test Yield	-	-	-	-	-	3/3/0	1/1/0	-

- QBS: Qual By Similarity
- Qual Device TPS563201DDCR is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- $\bullet \quad \text{The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles}\\$

TI Qualification ID: R-NPD-2307-003

Qualification Results

Туре	#	Test Name	Condition	Duration	Qual Device: TPS562208DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: TPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	1/77/0	-	-
UHAST	А3	Autoclave	121C/15psig	96 Hours	-	-	-	-	-	3/231/0	-
UHAST	A3	Unbiased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
UHAST	А3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	1/77/0	-	1/77/0
TC	A4	Temperature Cycle	-55C/125C	700 Cycles	-	-	-	3/231/0	3/231/0	-	1/77/0
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	-	-	3/231/0	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	1/77/0	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	3/231/0	-	-	-
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	-	3/231/0	1/77/0	-	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	-	3/2400/0	-	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: TPS562208DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: TPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
SD	СЗ	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB- Free Solder;	-	-	3/66/0	3/66/0	-	-	1/22/0	-
PD	C4	Physical Dimensions	(per mechanical drawing)	-	-	-	-	1/5/0	-	-	-
ESD	E2	ESD CDM	-	1500 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-	1/3/0	-	1/3/0
CHAR	E 5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	3/90/0	1/30/0	-	1/30/0
FTY	E6	Final Test Yield	-	-	-	-	-	3/3/0	1/1/0	-	-

- QBS: Qual By Similarity
 Qual Device TPS562208DDCR is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

TI Qualification ID: R-NPD-2307-024

Qualification Results

Туре	#	Test Name	Condition	Duration	Qual Device: TPS563208DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: IPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	1/77/0	-	-
UHAST	А3	Autoclave	121C/15psig	96 Hours	-	-	-	-	-	3/231/0	-
UHAST	A3	Unbiased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
UHAST	АЗ	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	1/77/0	-	1/77/0
тс	A4	Temperature Cycle	-55C/125C	700 Cycles	-	-	-	3/231/0	3/231/0	-	1/77/0
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	-	-	3/231/0	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	1/77/0	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	3/231/0	-	-	-
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	-	3/231/0	1/77/0	-	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	-	3/2400/0	-	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: TPS563208DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: TPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
SD	СЗ	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB- Free Solder;	-	-	3/66/0	3/66/0	-	-	1/22/0	-
PD	C4	Physical Dimensions	(per mechanical drawing)	-	-	-	-	1/5/0	-	-	-
ESD	E2	ESD CDM		1500 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-	1/3/0	-	1/3/0
CHAR	E 5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	3/90/0	1/30/0	-	1/30/0
FTY	E6	Final Test Yield	-	-	-	-	-	3/3/0	1/1/0	-	-

- QBS: Qual By Similarity
 Qual Device TPS563208DDCR is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/Ik Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47:-55C/125C/700 Cycles and -65C/150C/500 Cycles

TI Qualification ID: R-NPD-2307-025

Qualification Results

Туре	#	Test Name	Condition	Duration	Qual Device: TPS562201DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: TPS51393RJER	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	1/77/0	-	-
UHAST	АЗ	Autoclave	121C/15psig	96 Hours	-	-	-	-	-	3/231/0	-
UHAST	А3	Unbiased HAST	110C/85%RH	264 Hours	-	-	-	3/231/0	-	-	-
UHAST	А3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	1/77/0	-	1/77/0
TC	A4	Temperature Cycle	-55C/125C	700 Cycles	-	-	-	3/231/0	3/231/0	-	1/77/0
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	-	-	3/231/0	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	1/77/0	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	3/231/0	-	-	-
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	-	3/231/0	1/77/0	-	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	-	3/2400/0	-	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: TPS562201DDCR	QBS Reference: TPS563249DDCR	QBS Reference: TPS564201DDCR	QBS Reference: <u>TPS51393RJER</u>	QBS Reference: TPS563203DRLR	QBS Reference: TPS564201DDCR	QBS Reference: TPS563201DDCR
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB- Free Solder;	-	-	3/66/0	3/66/0	-	-	1/22/0	-
PD	C4	Physical Dimensions	(per mechanical drawing)	-	-	-	-	1/5/0	-	-	-
ESD	E2	ESD CDM	-	1500 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-	-	1/3/0	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-	1/3/0	-	1/3/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	3/90/0	1/30/0	-	1/30/0
FTY	E6	Final Test Yield	-	-	-	-	-	3/3/0	1/1/0	-	-

- QBS: Qual By Similarity
- Qual Device TPS562201DDCR is qualified at MSL1 260C
- . Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

TI Qualification ID: R-NPD-2307-012

For questions regarding this notice, e-mails can be sent to the Change Management team or your local Field Sales Representative.

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